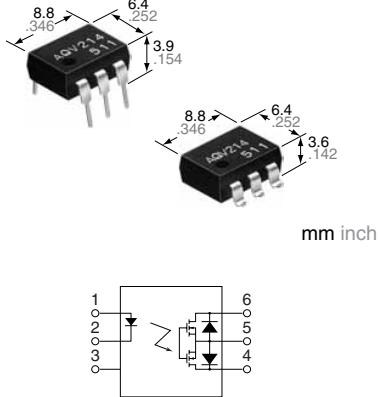


**Controls low-level
input signals.
Controls load voltage
60V to 600V.**

**GU PhotoMOS
(AQV21O, AQV214H)**



RoHS Directive compatibility information
<http://www.mew.co.jp/ac/e/environment/>

FEATURES

1. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

2. Control with low-level input signals

3. Controls various types of loads such as relays, motors, lamps and solenoids.

4. Optical coupling for extremely high isolation

Unlike mechanical relays, the PhotoMOS relay combines LED and optoelectronic device to transfer signals using light for extremely high isolation.

5. Eliminates the need for a counter electromotive force protection diode in the drive circuits on the input side

6. Stable on resistance

7. Low-level off state leakage current

8. Eliminates the need for a power supply to drive the power MOSFET

A power supply used to drive the power MOSFET is unnecessary because of the built-in optoelectronic device. This results in easy circuit design and small PC board area.

9. Low thermal electromotive force (Approx. 1 µV)

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Data communication equipment
- Computer

TYPES

Type	I/O isolation	Output rating*		Part No.				Packing quantity
				Through hole terminal		Surface-mount terminal		
		Load voltage	Load current	Tube packing style		Tape and reel packing style		
AC/DC	Standard 1,500 V AC	60V	550 mA	AQV212	AQV212A	AQV212AX	AQV212AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.
		100 V	320 mA	AQV215	AQV215A	AQV215AX	AQV215AZ	
		200 V	180 mA	AQV217	AQV217A	AQV217AX	AQV217AZ	
		350 V	130 mA	AQV210	AQV210A	AQV210AX	AQV210AZ	
		400 V	120 mA	AQV214	AQV214A	AQV214AX	AQV214AZ	
		600 V	50 mA	AQV216	AQV216A	AQV216AX	AQV216AZ	
	Reinforced 5,000 V	400 V	120 mA	AQV214H	AQV214HA	AQV214HAX	AQV214HAZ	

*Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV212(A)	AQV215(A)	AQV217(A)	AQV210(A)	AQV214(A)	AQV216(A)	AQV214H(A)	Remarks
Input	LED forward current	I _F		50 mA							
	LED reverse voltage	V _R		5 V							
	Peak forward current	I _{FP}		1 A					f = 100 Hz, Duty factor = 0.1%		
	Power dissipation	P _{in}		75 mW							
Output	Load voltage (peak AC)	V _L	A	60 V	100 V	200 V	350 V	400 V	600 V	400 V	A connection: Peak AC, DC; B, C connection: DC
	Continuous load current	I _L		0.55 A	0.32 A	0.18 A	0.13 A	0.12 A	0.05 A	0.12 A	
				0.65 A	0.42 A	0.22 A	0.15 A	0.13 A	0.06 A	0.13 A	
	Peak load current	I _{peak}	B	0.80 A	0.60 A	0.30 A	0.17 A	0.15 A	0.08 A	0.15 A	
	Power dissipation	P _{out}		1.2 A	0.96 A	0.54 A	0.4 A	0.3 A	0.15 A	0.3 A	
Total power dissipation		P _T	500 mW		550 mW						
I/O isolation voltage		V _{iso}	1,500 V AC		5,000 V AC						
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F						Non-condensing at low temp.		
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F								

GU PhotoMOS (AQV21O, AQV214H)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection**	AQV212(A)	AQV215(A)	AQV217(A)	AQV210(A)	AQV214(A)	AQV216(A)	AQV214H(A)	Condition
Input	LED operate current	Typical Maximum	I _{fon}	—	1 mA 3 mA	1 mA 3 mA	1 mA 3 mA	1 mA 3 mA	1 mA 3 mA	1 mA 3 mA	I _L = Max.
	LED turn off current	Minimum Typical	I _{loff}	—	0.4 mA 0.79 mA	0.4 mA 0.79 mA	0.4 mA 0.79 mA	0.4 mA 0.79 mA	0.4 mA 0.79 mA	0.4 mA 0.79 mA	I _L = Max.
Output	LED dropout voltage	Typical Maximum	V _F	—	1.25 V (1.14 V at I _F = 5 mA)						I _F = 50 mA
					1.5 V						
On resistance	Typical Maximum	R _{on}	A	0.83 Ω 2.5 Ω	2.3 Ω 4.0 Ω	11.0 Ω 15.0 Ω	23 Ω 35 Ω	30 Ω 50 Ω	70 Ω 120 Ω	30 Ω 50 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
	Typical Maximum	R _{on}	B	0.44 Ω 1.25 Ω	1.15 Ω 2.0 Ω	5.5 Ω 7.5 Ω	11.5 Ω 17.5 Ω	22.5 Ω 25 Ω	55 Ω 100 Ω	22.5 Ω 25 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
	Typical Maximum	R _{on}	C	0.25 Ω 0.63 Ω	0.6 Ω 1.0 Ω	2.8 Ω 3.8 Ω	6.0 Ω 8.8 Ω	11.3 Ω 12.5 Ω	28 Ω 50 Ω	11.3 Ω 12.5 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
	Output capacitance	Typical	C _{out}	A	150 pF	110 pF	70 pF	45 pF	45 pF	45 pF	I _F = 0 mA V _B = 0 V f = 1 MHz
	Off state leakage current	Maximum	—	—	1 μA						I _F = 0 mA V _L = Max.
Transfer characteristics	Switching speed	Turn on time* Maximum	T _{on}	—	0.65 ms 2 ms	0.6 ms 2 ms	0.25 ms 1.0 ms	0.25 ms 0.5 ms	0.21 ms 0.5 ms	0.28 ms 0.5 ms	I _F = 5 mA** I _L = Max.
	Turn off time*	Typical Maximum	T _{off}	—	0.08 ms 0.2 ms	0.06 ms 0.2 ms	0.05 ms 0.2 ms	0.05 ms 0.2 ms	0.05 ms 0.2 ms	0.04 ms 0.2 ms	I _F = 5 mA I _L = Max.
	I/O capacitance	Typical Maximum	C _{iso}	—	0.8 pF 1.5 pF						f = 1 MHz V _B = 0 V
	Initial I/O isolation resistance	Minimum	R _{iso}	—	1,000 MΩ						500 V DC

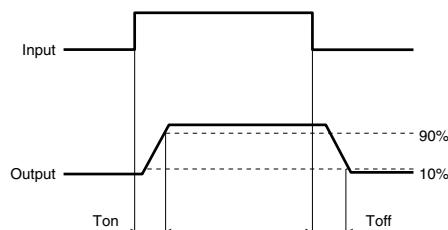
Note: Recommendable LED forward current

Standard type: I_F = 5 mA

Reinforced type: I_F = 5 mA

For type of connection.

*Turn on/Turn off time



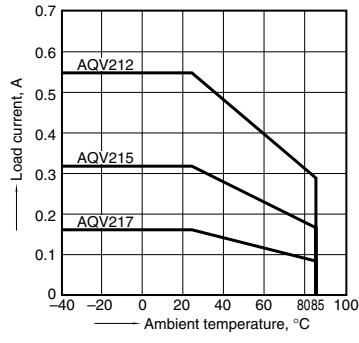
- For Dimensions.
- For Schematic and Wiring Diagrams.
- For Cautions for Use.

REFERENCE DATA

1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

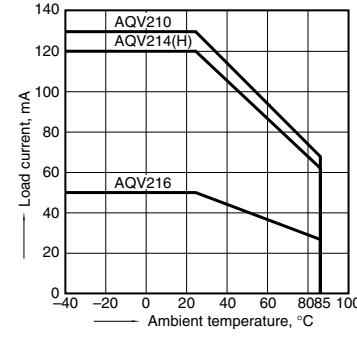
Type of connection: A



1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

Type of connection: A



2-(1). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Load voltage: Max. (DC)
Continuous load current: Max. (DC)

